



ZHEJIANG UNIU-NE Technology CO., LTD

浙江宇力微新能源科技有限公司



U3500C Data Sheet

V 1.3

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Switching Current Limit Step-Down Converter

General Description

The U3500C is a high-voltage, step-down, switching regulator that drives External power MOSFET. The input range accommodates a variety of step-down applications, making it ideal for automotive, industry, and lighting applications. Hysteretic voltage-mode control is employed for very fast response. UNI's proprietary feedback control scheme minimizes the number of required external components.

The switching frequency is 80KHz, allowing for small component size. Thermal shutdown and short-circuit shutdown (SCS) provide reliable and fault-tolerant operations. Low quiescent current allows the U3500C to be used in battery-powered applications.

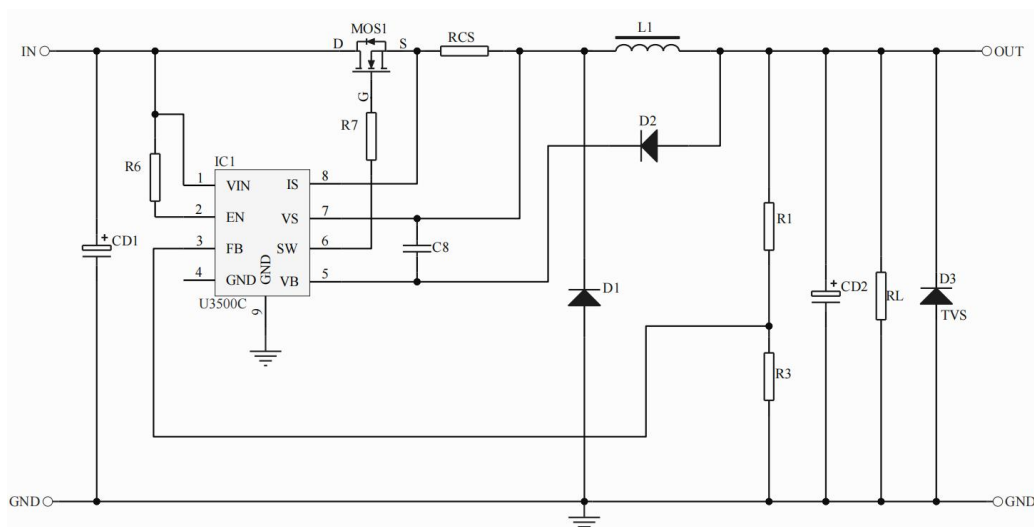
Key Features

- Internal integrated bootstrap power supply circuit
- DC-DC 12V Typical Switching Current Application
- Hysteretic Control: No Compensation
- 80KHz Switching Frequency
- PWM Control Input for step-down Application
- Short-Circuit Shutdown (SCS) with Integrated IC
- Low Quiescent Current
- Thermal Shutdown
- Available in a ESOP-8 Package with an Exposed Pad

Applications

- Scooters, E-Bike Control Power Supplies
- Solar Energy Systems
- Automotive System Power
- Industrial Power Supplies
- High-Power LED Drivers

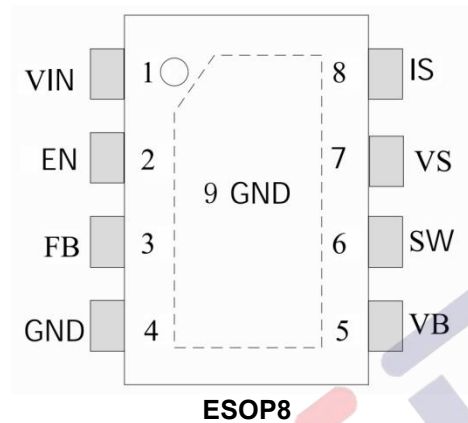
Typical Application



Ordering Information

Part Number	Package	Vo	VIN MAX	Load Current	Description
U3500C	ESOP-8	>2V	200V	Io<=10A	4000Pcs/Reel

Pin Description



Pin Functions

ESOP8 Pin #	Name	Description
1	VIN	Input supply. VIN supplies power to all of the internal control circuitries
2	EN	En input. Pull EN below the specified threshold or leave EN floating to shut down the U3500C. Pull EN above the specified threshold to enable the U3500C.
3	FB	Feedback. FB is the input to the voltage hysteretic comparators.
4	GND	The interior is connected to the GND (can be suspended)
5	VB	VB is the positive power supply for the internal, floating, high-side MOSFET driver. Connect a bypass capacitor between VB and VS.
6	SW	Switch node. SW is the output, drives External power MOSFET
7	VS	Switch source. Upper drive low potential
8	IS	Current detection. Current Sensing Input
9	EP-GND	Ground. GND should be placed as close to the output capacitor as possible to avoid the high current switch paths. Connect the exposed pad to GND plane for optimal thermal performance.

Block Diagram

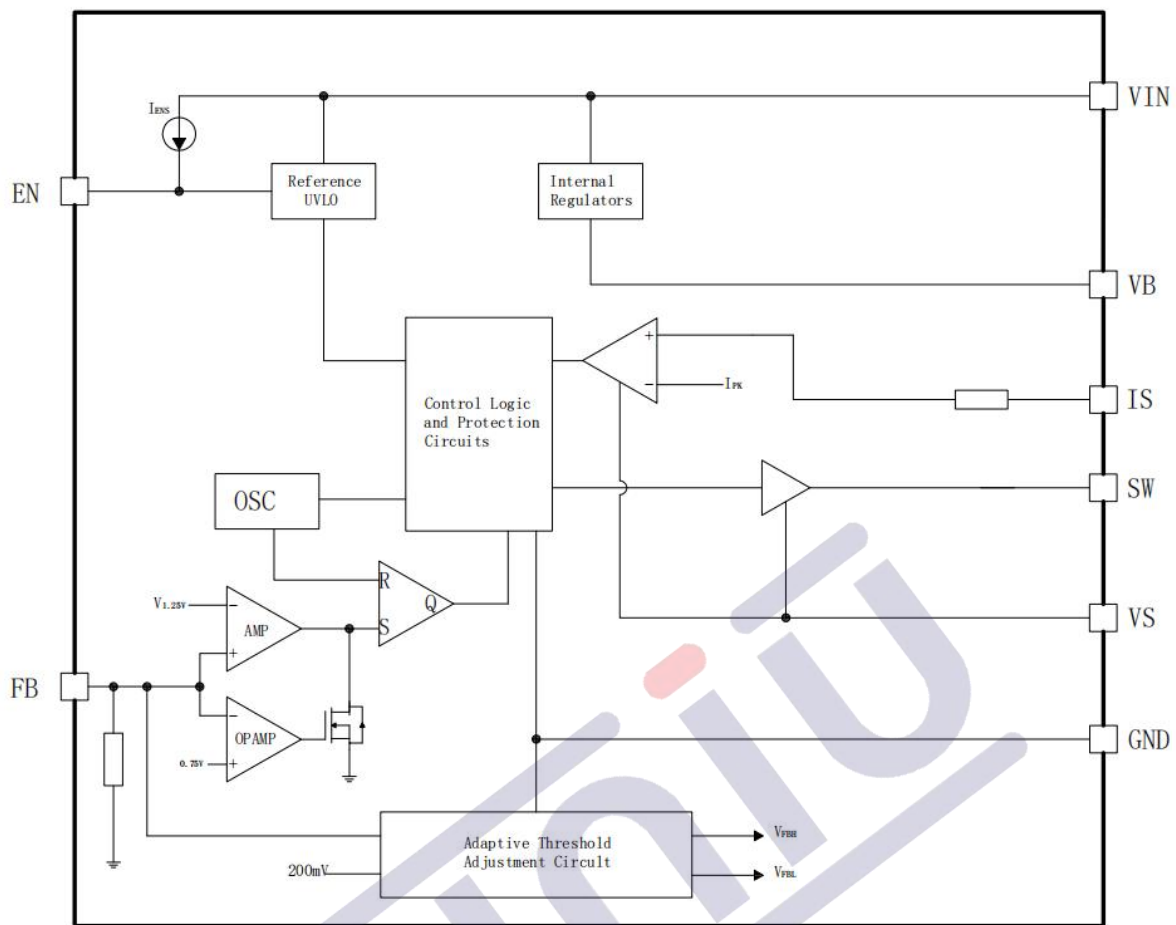


Figure 1:Function Block Diagram

Absolute Maximum Ratings (Note 1)

Parameter	Value	Unit
VIN,SW,VS, IS Pin Voltage Range	-0.3 to 200	V
VB Supply Voltage	200+20	V
FB,, EN Voltage Range	-0.3 to 7	V
Package Thermal Resistance ---Junction to Ambient (ESOP-8)	165	°C/W
Maximum Junction Temperature	160	°C
Storage Temperature Range	-65 to 150	°C
Lead Temperature (Soldering, 10sec.)	260	°C
ESD Capability, HBM (Human Body Model)	2	kV
ESD Capability, MM (Machine Model)	200	V

Note1: For electrostatic sensitive devices, pay attention to ESD prevention measures when operating them.

Electrical Characteristics

$V_{IN}=60V$, $T_A = +25^{\circ}C$, unless otherwise noted. Specifications over temperature are guaranteed by design and characterization.

Parameter	Symbol	Condition	Min	Typ	Max	Units
Shutdown supply current		$V_{EN} = 0V$	—	0.02	—	μA
Quiescent supply current		No load, DIM =low, $V_{FB}=1.3V$	—	0.5	—	mA
Drive source current	$I_{S(ON)}$		—	500	—	mA
leakage current	I_{SWLK}	$V_{EN} = 0V$, $V_{SW} = 0V$	—	0.02	1.5	μA
Peak current threshold	V_{IS}		—	250	—	mV
Working frequency	F_{SW}		—	80	—	KHz
EN -on	V_{ENH}		—	2.4	7	V
EN -off	V_{ENL}		—	—	1	V
EN threshold hysteresis	V_{ENHY}		—	500	—	mV
Feedback voltage threshold	V_{FBH}		1.25	1.3	—	V
FB to ground resistance	R_{FB}		—	50K	—	Ω
Thermal shutdown ⁽⁷⁾		Trigger thermal shutdown	—	150	—	$^{\circ}C$
		Hysteresis	—	20	—	

NOTES:

Note1:Stresses listed as the above “Maximum Ratings” may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note2:The device is not guaranteed to function outside its operating conditions.

Note3:Guaranteed by design.

Operation

Hysteresis Current Control with Adaptive Threshold Adjustment

The U3500C operates in a hysteretic voltage-control mode to regulate the output voltage. FB is connected to the tap of a resistor divider, which determines the output voltage. The power MOSFET is turned on when the FB voltage (V_{FB}) rises to FB-on and remains on until V_{FB} rises to FB-off. The power MOSFET is turned off when V_{FB} drops to FB-off and remains off until V_{FB} falls to FB-on. The two thresholds of FB-on and FB-off are adjusted adaptively to compensate for all the circuit delays, so the output voltage is regulated with an average 1.3V value at FB.

Floating Driver and Bootstrap Charging

The floating power MOSFET driver is powered by an external bootstrap capacitor.

The bootstrap capacitor is charged and regulated to about 12V by the dedicated internal bootstrap regulator.

If the internal circuit does not have sufficient voltage, and the bootstrap capacitor is not sufficiently charged, extra external circuitry can be used to ensure that the bootstrap voltage is in the normal operating region. Refer to the External Bootstrap Diode section for more details.

Fast charging Function for USB Applications

Because the FB reference of the U3500C is very flexible, it is recommended to use the U3500C for USB Fast charging Applications by connecting the current sense resistor between FB and GND.

Thermal Shutdown

Thermal shutdown is implemented to prevent the chip from operating at exceedingly high temperatures. When the silicon die temperature is higher than its upper threshold, the entire chip shuts down. When the temperature is lower than its lower threshold, the chip is enabled again.

Output Short Shutdown Protection

The output voltage is well-regulated when V_{FB} is around 1.3V. If the output is pulled Shutdown in over-current protection (OCSP) or is shorted to GND directly, V_{FB} is low, Until the power MOSFET is turned on again. The U3500C regards the low V_{FB} as a failure. The power MOSFET is pulled Shutdown if the failure time is longer .

The power MOSFET current is also accurately sensed via a current sense MOSFET. If the current is over the current limit, the IC is pulled Shutdown. This offers extra protection under output-short conditions.

Application Information

Setting the Output Voltage

The output voltage (V_{OUT}) is set by a resistor divider ($R1$ and $R2$) (see the Typical Application on page 1). To achieve good noise immunity and low power loss, $R2$ is recommended to be in the range of $1k\Omega$ to $50k\Omega$. $R1$ can then be determined with Equation (1):

$$R1 = \frac{V_{OUT} - V_{FB}}{V_{FB}} \times R2 \quad (1)$$

Where V_{FB} is 1.3V, typically.

FB has 50K resistance inside, and the calculation is in parallel with $R2$

Output Capacitor and Frequency Setting

The output capacitor (C_{OUT}) is necessary for achieving a smooth output voltage. The ESR of the capacitor should be sufficiently large compared to the capacitance; otherwise, the system may behave in an unexpected way, and the current ripple may be very high. V_{FB} changes from 1.25V to 1.35V when the power MOSFET switches on. To charge the capacitor and generate 1.35V at FB, the system needs ESR and some inductor current. For example, for a 5V V_{OUT} , if the forward capacitor is $0.1\mu F$, the suggested ESR range of the output capacitor is $100m\Omega$ to $250m\Omega$. Tantalum or aluminum electrolytic capacitors with a small ceramic capacitor are recommended.

A forward capacitor across $R1$ is recommended when the output capacitor is tantalum or aluminum electrolytic, which can set the desired frequency if the output capacitor and ESR cannot be changed. The forward capacitor can reduce the output voltage ripple.

In some application, simply a forward capacitor may not get proper frequency, then we can add a forward resistor in series with the forward capacitor or even more add a ceramic on the output.

Selecting the Inductor

The inductor (L) is required to convert the switching voltage to a smooth current to the load. Although the output current is low, it is recommended that the inductor current be continuous in each switching period to prevent reaching the current limit. Calculate the inductor value with Equation (2):

$$L = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{F_{SW} \times I_{OUT} \times V_{IN} \times K} \quad (2)$$

Where K is a coefficient of about 0.15 ~ 0.85

Output Rectifier Diode

The output rectifier diode supplies current to the inductor when the high-side switch is off. To reduce losses due to the diode forward voltage and recovery times, use a Schottky diode. The average current through the diode can be approximated with Equation (3):

$$I_D = I_{OUT} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (3)$$

Choose a diode with a maximum reverse voltage rating greater than the maximum input voltage and a current rating is greater than the average diode current.

Peak current regulation

Current estimation formula(4)

$$I_{PK} = \frac{V_{IPK}}{R_{CS}} = \frac{0.25V}{R_{CS}} \quad (4)$$

Note: The voltage calculation will be affected by the freewheeling diode, and the actual debugging shall prevail

Input Capacitor (C_{IN})

The input current to the step-down converter is discontinuous and therefore requires a capacitor to supply AC current to the step-down converter while maintaining the DC input voltage. Use low ESR capacitors for the best performance, especially under high switching frequency applications.

The RMS current through the input capacitor (5):

$$I_{IN_AC} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)} \quad (5)$$

With low ESR capacitors, the input voltage ripple can be estimated with Equation (6):

$$\Delta V_{IN} = \frac{I_{OUT} \times V_{OUT}}{F_{SW} \times C_{IN} \times V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (6)$$

Choose an input capacitor with enough RMS current rating and enough capacitance for small input voltage ripples.

When electrolytic or tantalum capacitors are applied, a small, high-quality ceramic capacitor (i.e.: 0.1 μ F) should be placed as close to the IC as possible.

External Bootstrap Diode

An external bootstrap diode may enhance the efficiency of the converter (see Figure 2). An external VB diode is recommended from the VB supply to VB in the following cases:

- There is a 12V rail available in the system
- IO is greater than 1A

This diode is also recommended for high duty cycle operations (when $V_{OUT} / V_{IN} > 65\%$) and very high frequency applications.

The bootstrap diode can be a low-cost one, such as FR107.

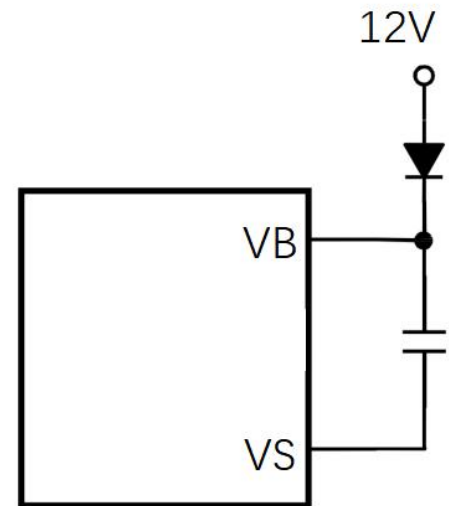


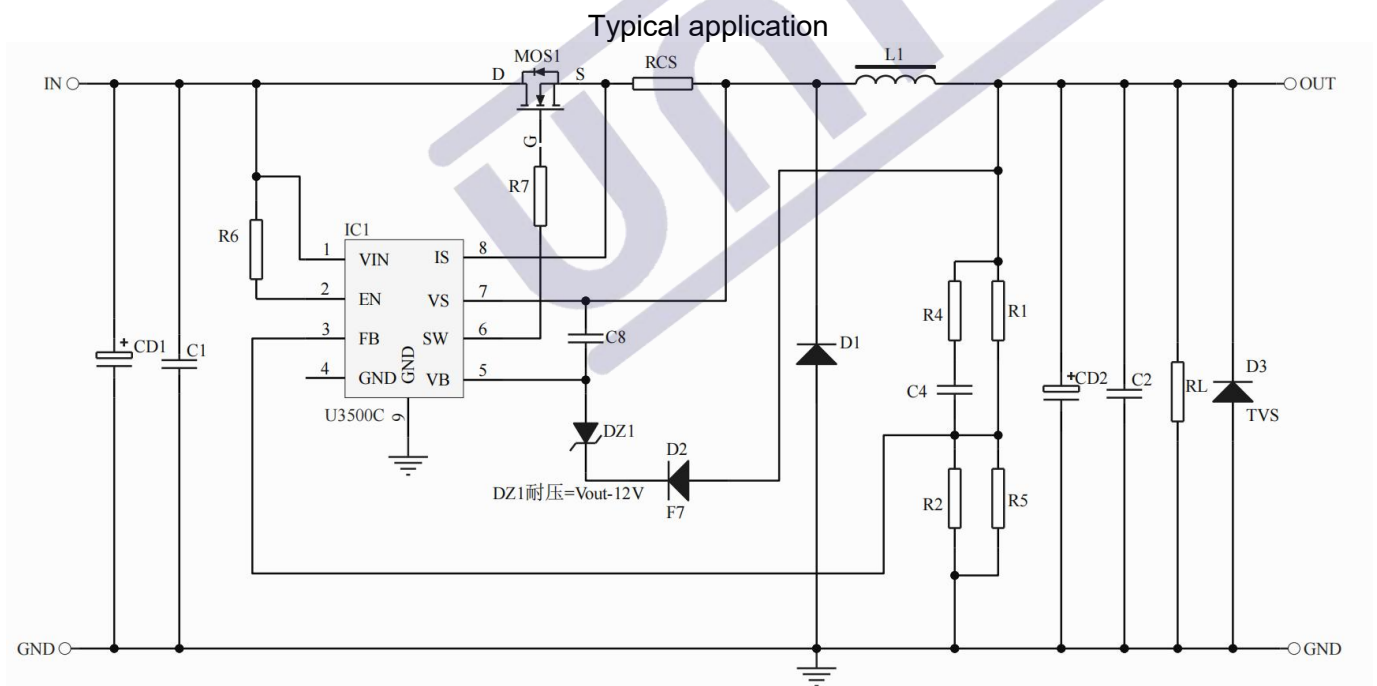
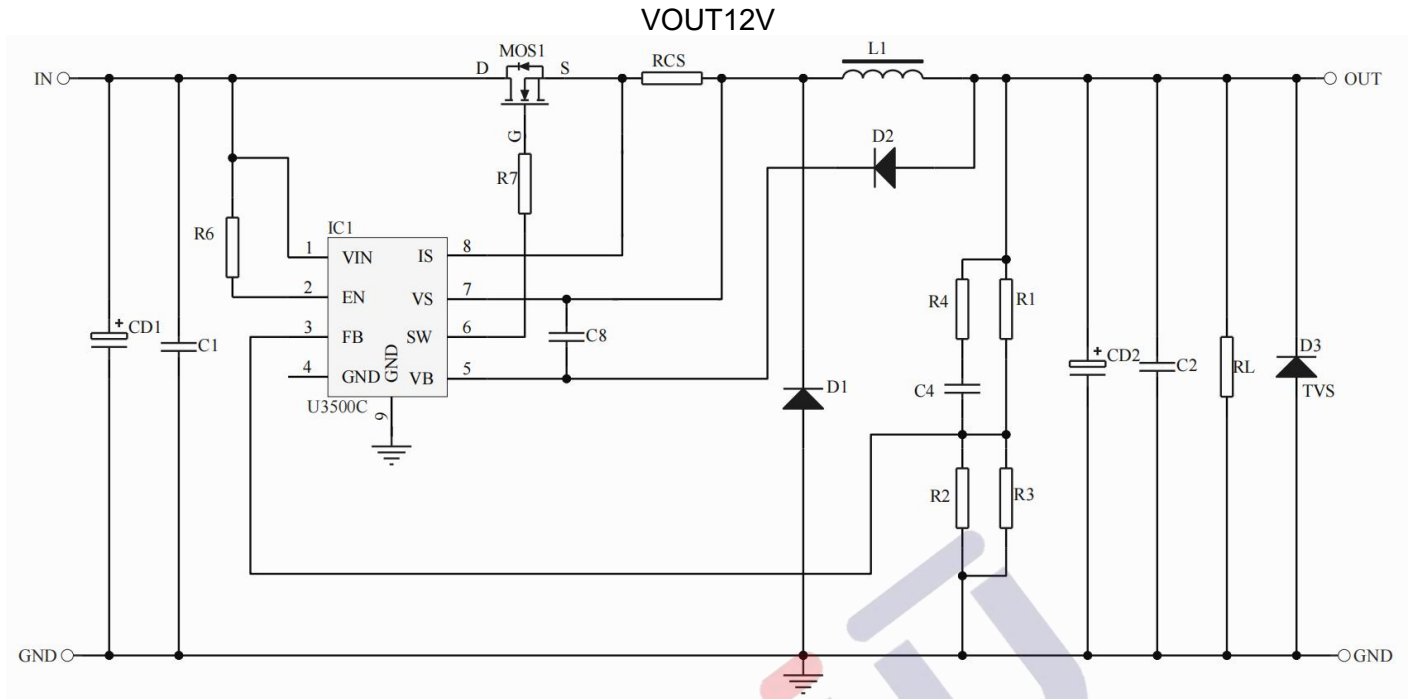
Figure 2: External Bootstrap Diode

PCB Layout Guidelines

Efficient PCB layout is critical for stable operation. For best results, follow the guidelines below.

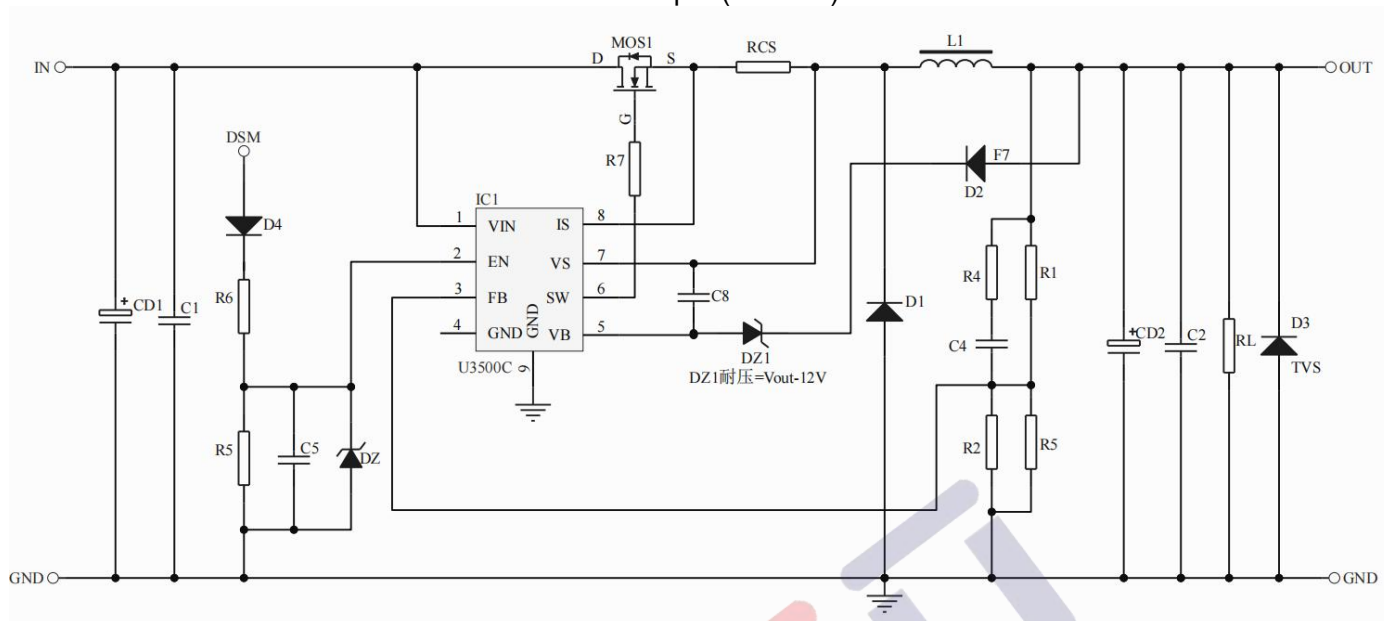
1. Place the input decoupling capacitor, catch diode, and the U3500C (VIN, SW, and PGND) as close to each other as possible.
2. Keep the power traces very short and fairly wide, especially for the SW node. This can help greatly reduce voltage spikes on the SW node and lower the EMI noise level.
3. Run the feedback trace as far from the inductor and noisy power traces (like the SW node) as possible.
4. Place thermal vias with 15mil barrel diameter and 40mil pitch (distance between the centers) under the exposed pad to improve thermal conduction.

Typical Application Circuit

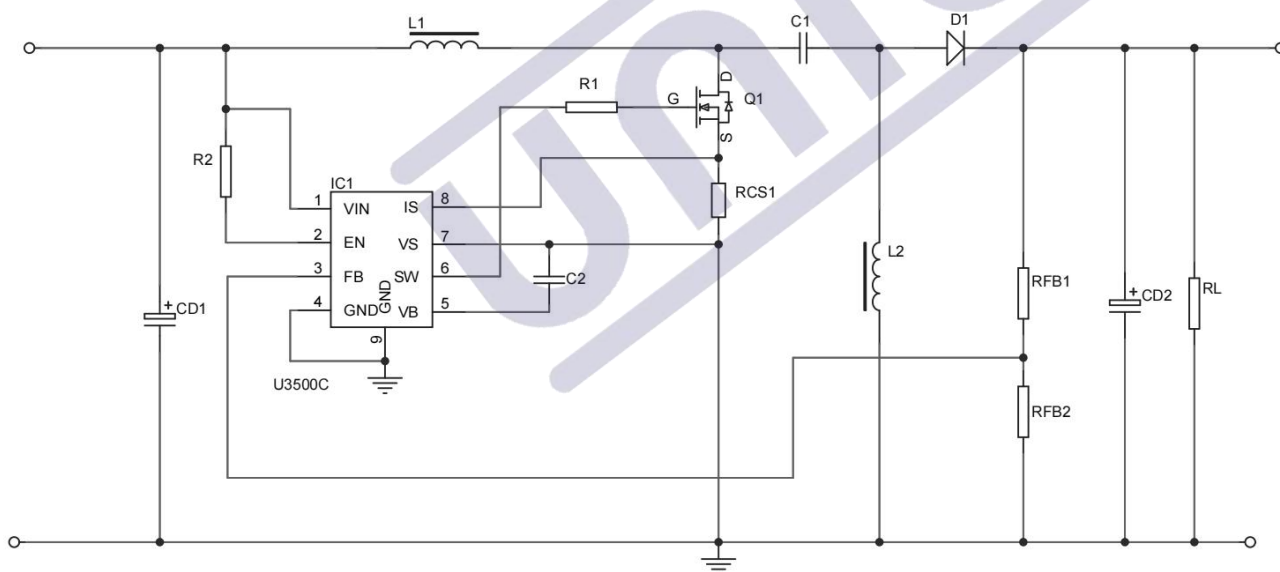


If $V_{OUT} < 15V$, DZ1 in the application diagram is not added,
if $V_{OUT} > 15V$, please use the appropriate voltage regulator diode according to the application diagram.

Enable input (four line):



Application of step-up and step-down voltage.

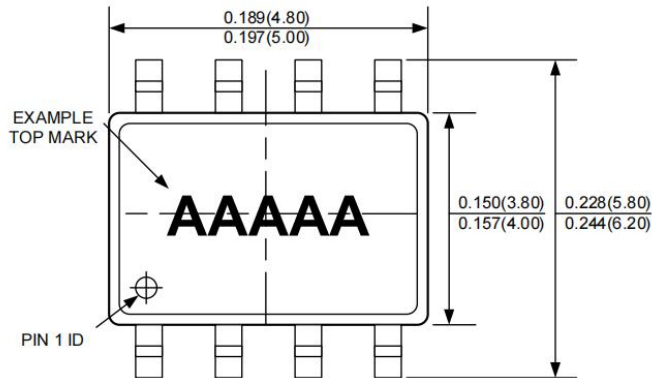


Note:

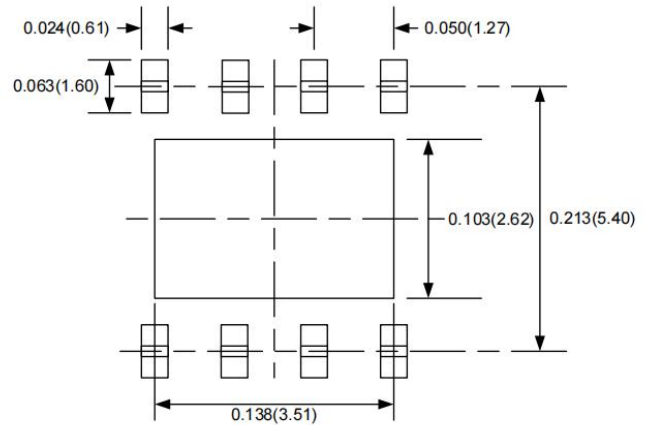
1. Typical application circuit and parameters for reference, the actual application circuit parameters please set on the basis of measurement, mass production please communicate with the original factory, other unknown please contact our engineers.
2. Input electrolytic capacitor (CE1) and continuous current diode (D1) according to the actual use of voltage, current to adjust.

Package Information

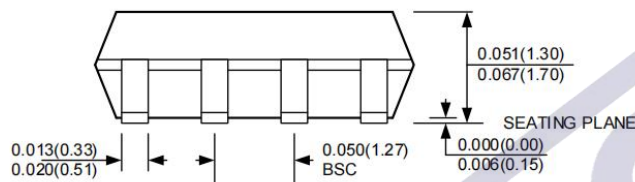
ESOP8 (EXPOSED PAD)



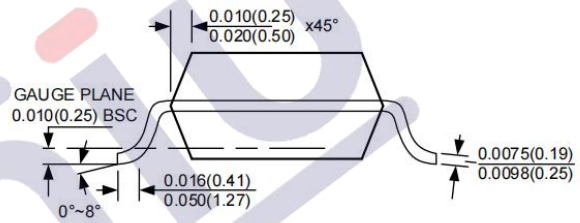
TOP VIEW



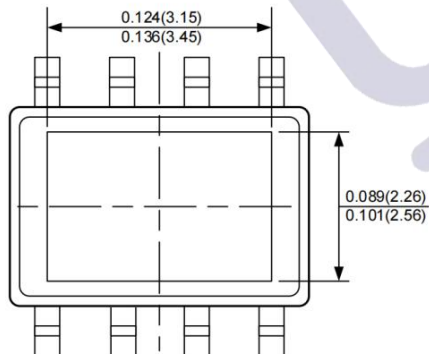
RECOMMENDED PAD LAYOUT



FRONT VIEW



SIDE VIEW



BOTTOM VIEW

NOTE:

- 1.CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2.PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3.PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4.LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5.DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA.
- 6.DRAWING IS NOT TO SCALE

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1、版本记录

DATE	REV.	DESCRIPTION
2023/7/25	1.0	首次发布
2023/10/10	1.1	增加小功率电路
2023/11/08	1.2	增加使能输入的应用电路
2024/03/26	1.3	增加IPK计算公式和升降压应用电路

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